



MMBD4448DW

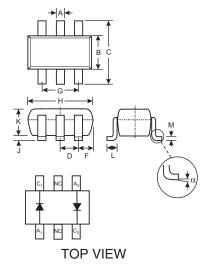
SURFACE MOUNT SWITCHING DIODE

Features

- Fast Switching Speed
- Surface Mount Package Ideally Suited for Automatic Insertion
- For General Purpose Switching Applications
- High Conductance
- Ultra Miniature Package
- Lead Free/RoHS Compliant (Note 3)

Mechanical Data

- Case: SOT-363
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Polarity: See Diagram
- Marking: KA3 (See Page 3)
- Weight: 0.006 grams (approx.)



SOT-363								
Dim	Min	Max						
Α	0.10	0.30						
В	1.15	1.35						
С	2.00 2.20							
D	0.65 Nominal							
F	0.30	0.40						
н	1.80	2.20						
J	_	0.10						
к	0.90	1.00						
L	0.25	0.40						
М	0.10	0.25						
α	0°	8°						
All Dimensions in mm								

Maximum Ratings @ $T_A = 25^{\circ}C$ unless otherwise specified

Characteristic	Symbol	Value	Unit							
Non-Repetitive Peak Reverse Voltage	V _{RM}	100	V							
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	75	V							
RMS Reverse Voltage	V _{R(RMS)}	53	V							
Forward Continuous Current (Note 1)	I _{FM}	500	mA							
Average Rectified Output Current (Note 1)	Ι _Ο	250	mA							
Non-Repetitive Peak Forward Surge Current $@t < 1\mu s$ @t < 1s	I _{FSM}	4 2	А							
Power Dissipation (Note 1)	Pd	200	mW							
Thermal Resistance Junction to Ambient Air (Note 1)	$R_{ heta JA}$	625	°C/W							
Operating and Storage Temperature Range	T_{j} , T_{STG}	-65 to +150	°C							

Electrical Characteristics @ T_A = 25°C unless otherwise specified

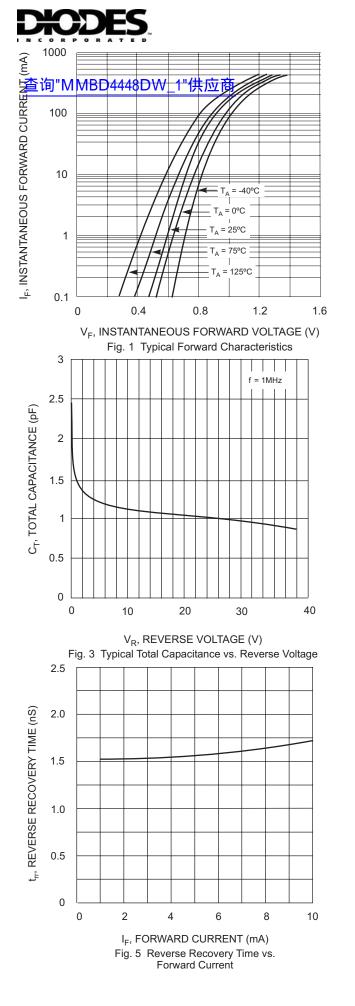
Characteristic	Symbol	Min	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 2)	V _{(BR)R}	75		V	I _R = 10μA
Forward Voltage	V _F	0.62	0.720 0.855 1.0 1.25	V	$\begin{array}{l} I_F=5.0mA\\ I_F=10mA\\ I_F=50mA\\ I_F=150mA \end{array}$
Reverse Current (Note 2)	I _R		2.5 50 30 25	μΑ μΑ μΑ nA	$ \begin{array}{l} V_{R} = 75V \\ V_{R} = 75V, \ T_{j} = 150^{\circ}C \\ V_{R} = 25V, \ T_{j} = 150^{\circ}C \\ V_{R} = 20V \end{array} $
Total Capacitance	CT	_	4.0	pF	V _R = 0, f = 1.0MHz
Reverse Recovery Time	t _{rr}	—	4.0	ns	$\label{eq:lf} \begin{array}{l} I_F = I_R = 10 \text{mA}, \\ I_{rr} = 0.1 \text{ x } I_R, \ R_L = 100 \Omega \end{array}$

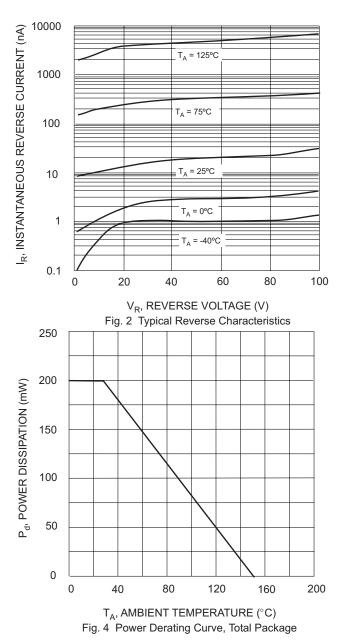
Notes: 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout

document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

2. Short duration test pulse used to minimize self-heating.

3. No purposefully added lead.





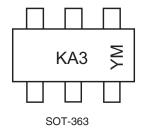


Ordering Information (Note 4)

查询"MMBD44480~~1"供应商	Packaging	Shipping		
MMBD4448DW-7-F	SOT-363	3000/Tape & Reel		

Notes: 4. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



KA3 = Product Type Marking Code, YM = Date Code Marking Y = Year ex: N = 2002 M = Month ex: 9 = September

Date Code Key

Year	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	L	М	N	Р	R	S	Т	U	V	W	Х	Y	Z
Month		Jan	Feb	March	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code		1	2	3	4	5	6	7	8	9	0	N	D

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